



Author Correction: Vapour-deposited high-performance tin perovskite transistors

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Check for updates

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In the version of the article initially published, in Fig. 4f, the images for “Vapour deposition” and “Solution processing” were switched and have now been amended in the HTML and PDF versions of the article, as seen in Fig. 1.

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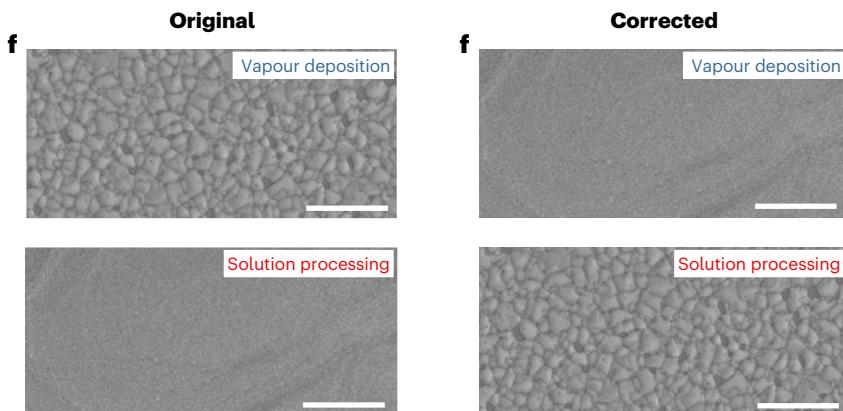


Fig. 1 | Original and corrected Fig. 4f.